

Form PTO-1449 (REV. 8-83)		US Dept. of Commerce PATENT & TRADEMARK OFFICE		ATTY DOCKET NO. 118008		APPLICATION NO. 10/728,746	
INFORMATION DISCLOSURE STATEMENT  (Use several sheets if necessary)				APPLICANT Kanji NATORI		GROUP ART UNIT <del>2818</del> 2827	
				FILING DATE December 8, 2003		EXAMINER S. Mai	
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB CLASS	
OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)							
<i>JL</i>	1	Wei-Ming Chen et al., "A Novel Flash Memory Device with Split Gate Source Side Injection and ONO Charge Storage Stack (SPIN)", 1997 Symposium on VLSI Technology Digest of Technical Papers, Pgs. 63-64.					
EXAMINER				DATE CONSIDERED			
SON MAI				03/31/05			
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							